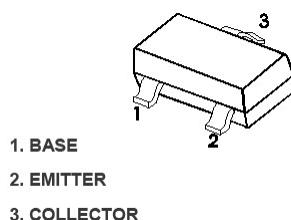


SOT-23**SOT-23 贴片塑封三极管  
SOT-23 Plastic-Encapsulate Transistors****Marking: J8****特征 Features**

- AM/FM Amplifier, Local Oscillator of FM/VHF Tuner
- 最大功率耗散 200mW; Power Dissipation of 200mW
- 高稳定性和可靠性。High Stability and High Reliability

**机械数据 Mechanical Data**

- 封装: SOT-23 封装 SOT-23 Small Outline Plastic Package
- 环氧树脂 UL 易燃等级 Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any

极限值和温度特性(TA = 25°C 除非另有规定)

**Maximum Ratings & Thermal Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified.)

参数 Parameters	符号 Symbol	数值 Value	单位 Unit
Collector-Base Voltage	V <sub>CBO</sub>	30	V
Collector-Emitter Voltage	V <sub>CEO</sub>	15	V
Emitter -Base Voltage	V <sub>EBO</sub>	5	V
Collector Current-Continuous	I <sub>c</sub>	50	mA
Collector Power Dissipation	P <sub>c</sub>	200	mW
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55~+150	°C
Thermal resistance From junction to ambient	R <sub>θJA</sub>	625	°C/W

电特性 (TA = 25°C 除非另有规定)

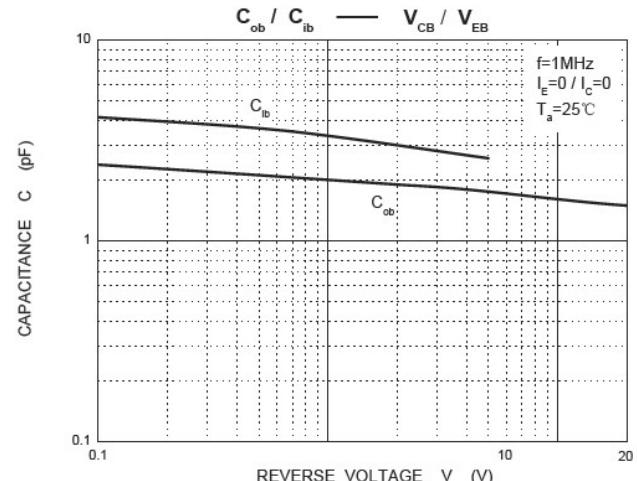
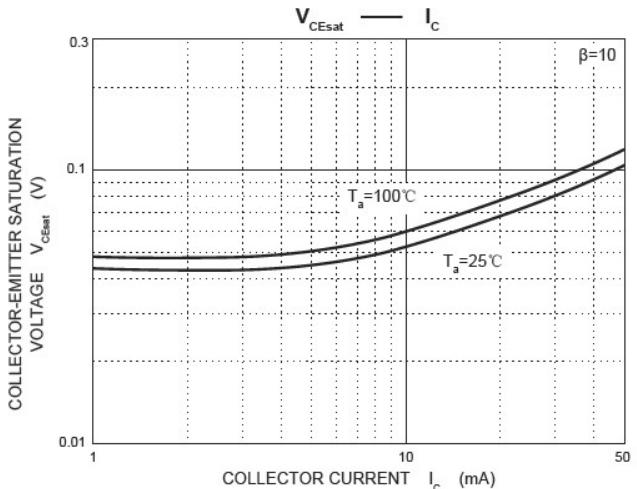
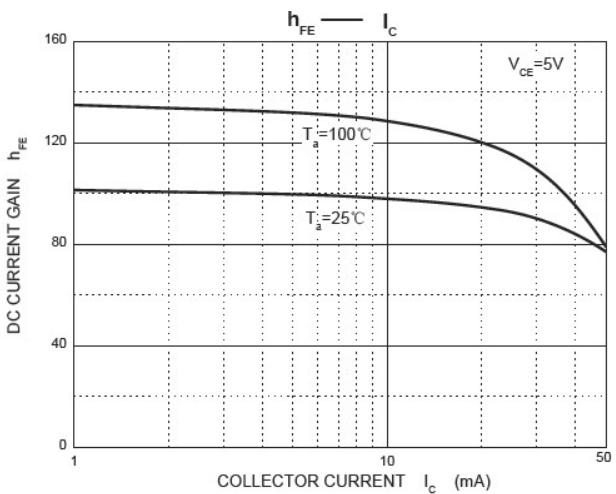
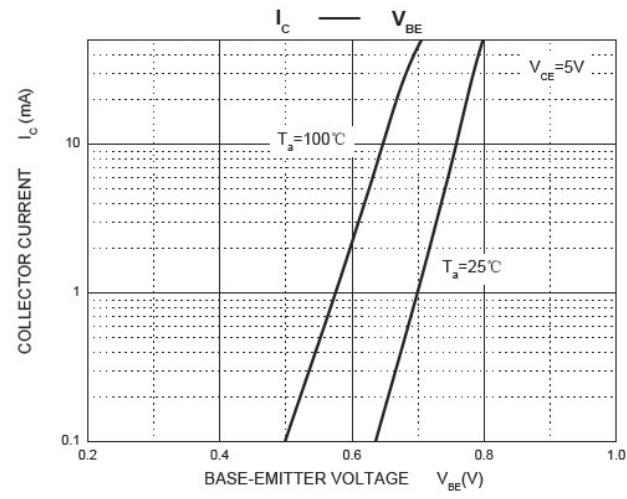
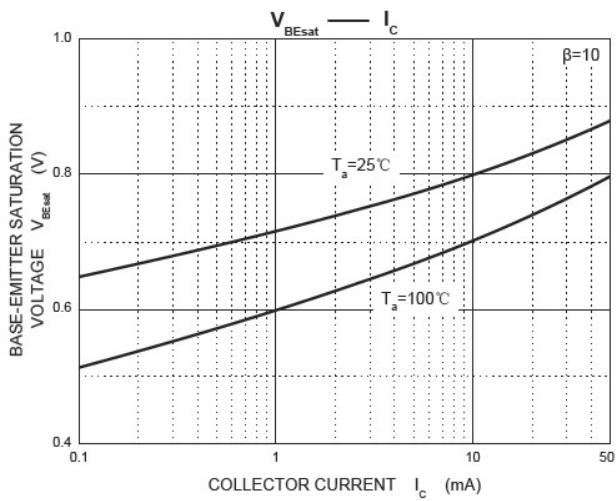
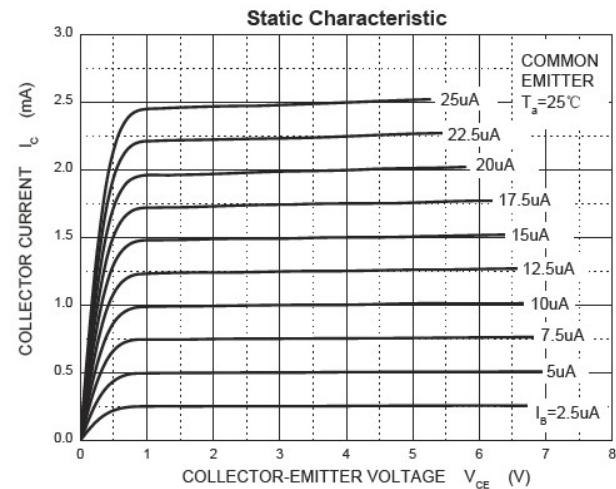
**Electrical Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified).

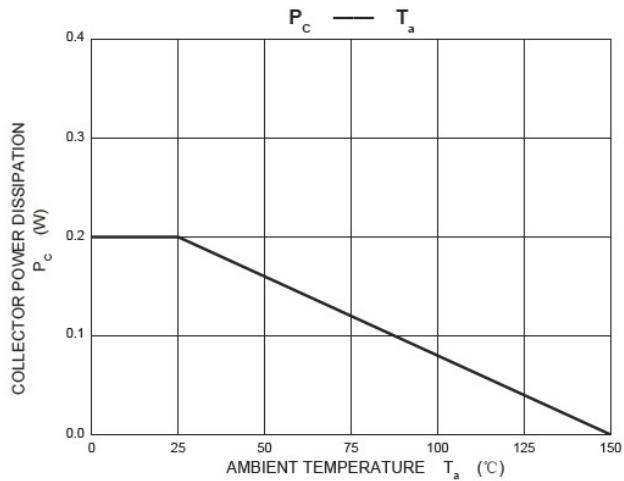
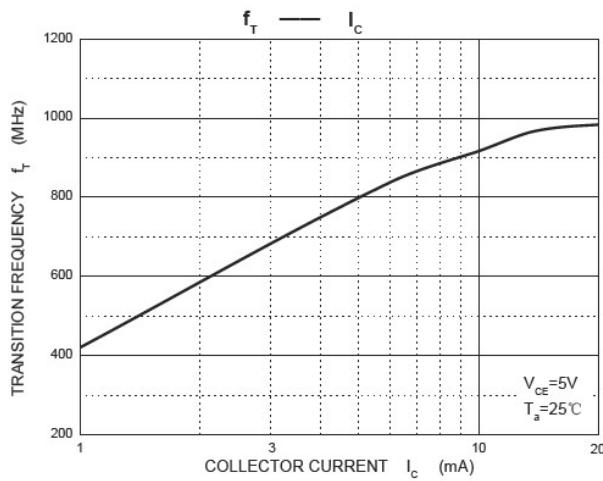
参数 Parameter	符号 Symbols	测试条件 Test Condition	界限 Limits			单位 Unit
			Min	Typ	Max	
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>c</sub> =100μA, I <sub>e</sub> =0	30			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>c</sub> =1mA, I <sub>b</sub> =0	15			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>e</sub> =100μA, I <sub>c</sub> =0	5			V
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =12V, I <sub>b</sub> =0			100	nA
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =12V, I <sub>e</sub> =0			50	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =3V, I <sub>c</sub> =0			100	nA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>c</sub> =1mA	70		190	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>c</sub> =10mA, I <sub>b</sub> =1mA			0.50	V
Base -emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>c</sub> =10mA, I <sub>b</sub> =1mA			1.40	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>c</sub> =5mA,f=400MHz		800		MHz

**CLASSIFICATION OF h<sub>FE</sub>**

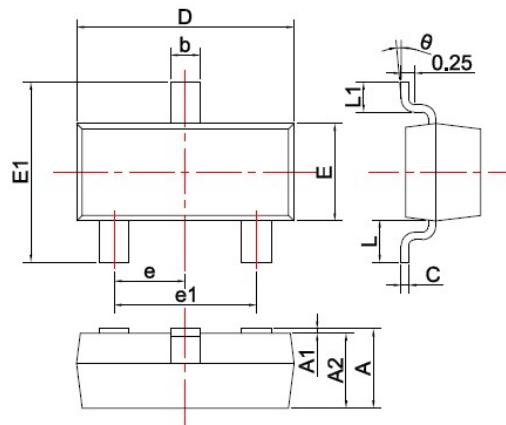
RANK	L	H
RANGE	70-105	105-190

## Typical characteristics





### SOT-23 PACKAGE OUTLINE Plastic surface mounted package

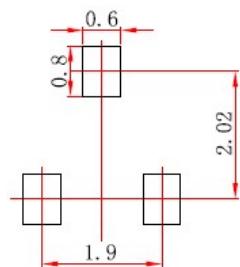


SYMBOL	DIMENSIONS	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

Unit: mm

### 焊盘设计参考 Precautions: PCB Design

Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs



#### Note:

1. Controlling dimension: In millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.